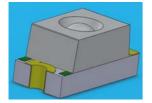
DATASHEET

EVERLIGHT

1206 Package Phototransistor With Inner Lens PT11-21C/L41/TR8



Features

- Fast response time
- High photo sensitivity
- Small junction capacitance
- Package in 8mm tape on 7" diameter reel
- Pb free
- The product itself will remain within RoHS compliant version
- Compliance with EU REACH

Descriptions

- PT11-21C/L41/TR8 is a phototransistor in miniature SMD package which is molded in a black with flat top view lens.
- The device is Spectrally matched to visible and infrared emitting diode.

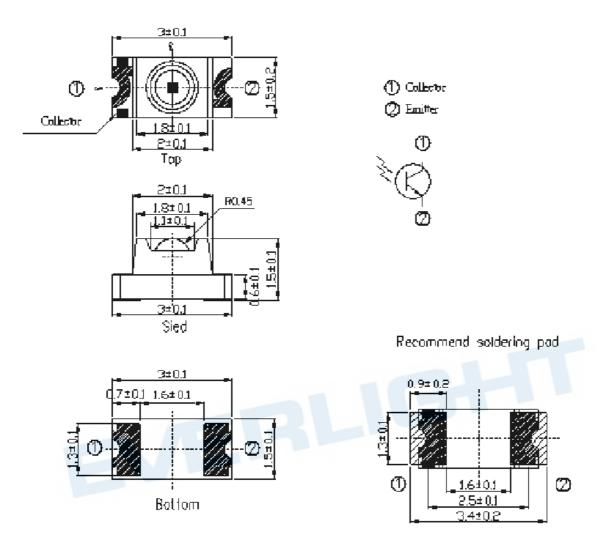
Applications

- Automatic door sensor
- Coper
- Game machine
- Infrared applied system

Device Selection Guide

Part No.	Chip Material	Lens Color		
PT	Silicon	Water clear		

Package Dimensions



Notes: 1.All dimensions are in millimeters

- 2.Tolerances unless dimensions ±0.1mm
- 3.Suggested pad dimension is just for reference only Please modify the pad dimension based on individual need

Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Rating	Units			
Collector-Emitter Voltage	Vceo	30	V			
Emitter-Collector-Voltage	Veco	5	V			
Collector Current	lc	20	mA			
Operating Temperature	T _{opr}	-25 ~ +85	°C			
Storage Temperature	T _{stg}	-40 ~ +85	°C			
Soldering Temperature *1	T _{sol}	260	°C			
Power Dissipation at(or below) 25°C Free Air Temperature	Pd	75	mW			

Notes: *1: Soldering time \leq 5 seconds

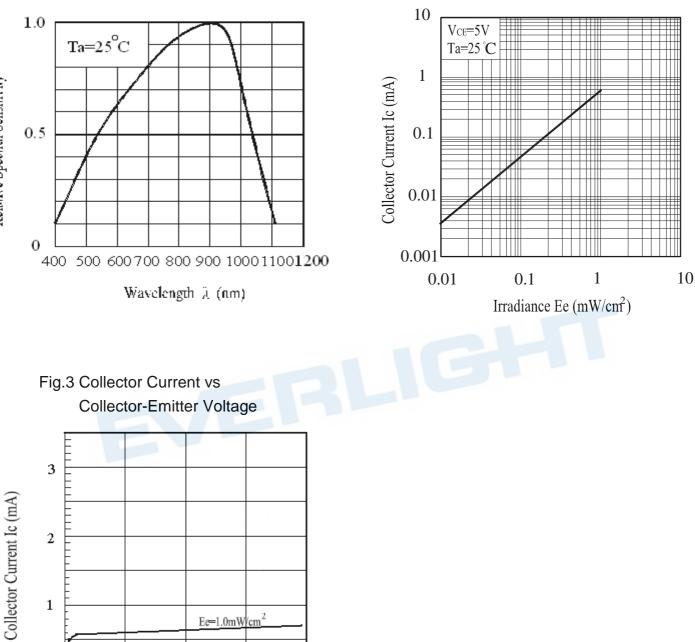
Electro-Optical Characteristics (Ta=25°C)

Parameter	Symbol	Condition	Min.	Тур.	Max.	Units
Range of Spectral Bandwidth	λ0.5		530	ļ	1030	nm
Wavelength of Peak Sensitivity	λP			940		nm
Collector-Emitter Breakdown Voltage	BVCEO	Ic=100µA Ee=0mW/cm ²	30			V
Emitter-Collector Breakdown Voltage	BV _{ECO}	I _E =100μA Ee=0mW/cm ²	5			V
Collector-Emitter Saturation Voltage	Vce(sat)	Ic=2mA Ee=1m W/cm ²			0.4	V
Collector Dark Current	Iceo	V _{CE} =20V Ee=0mW/cm ²			100	nA
On State Collector Current	Ic(on)	$V_{CE}=5V$ Ee=1mW/cm ²	0.3	0.8		mA

Typical Electro-Optical Characteristics Curves



Fig.2 Collector Current vs Irradiance



Collector-Emitter Voltage VCE (V)

2

0

0

1

3

4

Precautions For Use

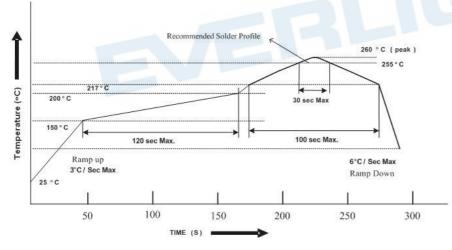
1. Over-current-proof

Customer must apply resistors for protection, otherwise slight voltage shift will cause big current change (Burn out will happen).

- 2.1 Do not open moisture proof bag before the products are ready to use.
- 2.2 Before opening the package: The LEDs should be kept at 10° C $\sim 30^{\circ}$ C and 90%RH or less.
- 2.3 The Phototransistor suggested be used within one year.
- 2.4 After opening the package, the devices must be stored at 10°C~30°C and ≤ 60% RH , and used within 168 hours (floor life). If unused Phototransistor remain, it should be stored in moisture proof packages.
- 2.5 I lf the moisture absorbent material (desiccant material) has faded or unopened bag has exceeded the shelf life or devices (out of bag) have exceeded the floor life, baking treatment is required.
- 2.6 If baking is required , refer to IPC/JEDEC J-STD-033 for bake procedure or recommend the following conditions:

96 hours at 60 $^\circ$ C \pm 5 $^\circ$ C and <5%RH(reeled/tubed/loose units)

- 3. Soldering Condition
 - 3.1 Pb-free solder temperature profile



- 3.2 Reflow soldering should not be done more than two times.
- 3.3 When soldering, do not put stress on the Phototransistor during heating.
- 3.4 After soldering, do not warp the circuit board.

Data Sheet 1206 Package Phototransistor With Inner Lens PT11-21C/L41/TR8

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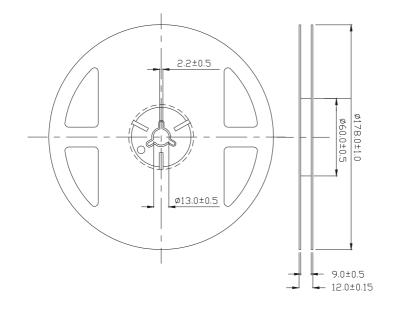
4. Soldering Iron

Each terminal is to go to the tip of soldering iron temperature less than 350° for 3 seconds within once in less than the soldering iron capacity 25W. Leave two seconds and more intervals, and do soldering of each terminal. Be careful because the damage of the product is often started at the time of the hand solder.

5. Repairing

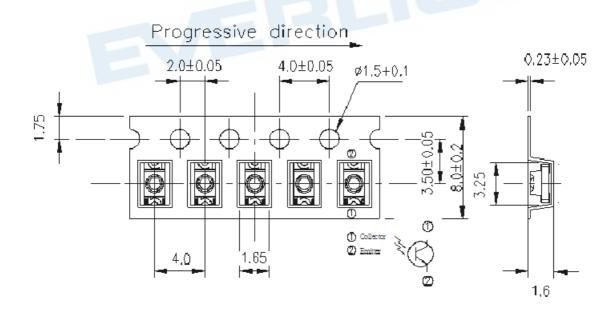
Repair should not be done after the Phototransistor have been soldered. When repairing is unavoidable, a double-head soldering iron should be used (as below figure). It should be confirmed beforehand whether the characteristics of the Phototransistor will or will not be damaged by repairing.

Package Dimensions



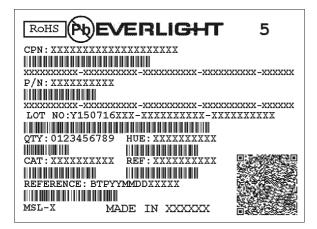
Note: The tolerances unless mentioned are ±0.1mm, Unit: mm

Carrier Tape Dimensions: (Loaded Quantity: 3000pcs/reel)



Note: The tolerances unless mentioned are ±0.1mm, Unit: mm

Label Form Specification



CPN: Customer's Production Number P/N : Production Number QTY: Packing Quantity CAT: Ranks HUE: Peak Wavelength REF: Reference LOT No: Lot Number MSL-X: MSL Level Made In: Manufacture place

Notes

- 1. EVERLIGHT reserves the right(s) on the adjustment of product material mix for the specification.
- 2. The product meets EVERLIGHT published specification for a period of twelve (12) months from date of shipment.
- 3. The graphs shown in this datasheet are representing typical data only and do not show guaranteed values.
- 4. When using this product, please observe the absolute maximum ratings and the instructions for use outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
- 5. These specification sheets include materials protected under copyright of EVERLIGHT. Reproduction in any form is prohibited without the specific consent of EVERLIGHT.
- 6.This product is not intended to be used for military, aircraft, automotive, medical, life sustaining or life saving applications or any other application which can result in human injury or death. Please contact authorized Everlight sales agent for special application request.

EVERLIGHT ELECTRONICS CO., LTD. Office: No. 6-8, Zhonghua Rd., Shulin Dist.,

New Taipei City 23860, Taiwan

Tel: 886-2-2685-6688 Fax: 886-2685-2699,6897

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